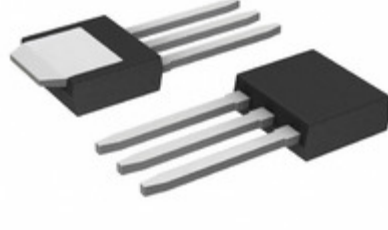


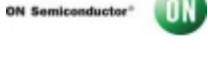
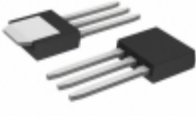
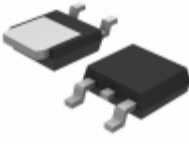
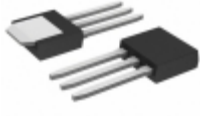
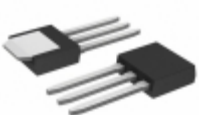
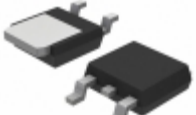
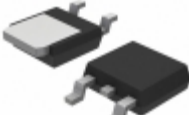
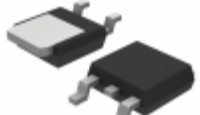
	<h2 style="color: red;">NTD32N06L-1G</h2>
	<p>Hersteller-Teilenummer: NTD32N06L-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 32A IPAK</p> <p>Datenblätter:  NTD32N06L-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 5000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD32N06L-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 60V 32A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	5000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	1.5W (Ta), 93.75W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	32A (Ta)
Rds On (Max) @ Id, Vgs	28 mOhm @ 16A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	50nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1700pF @ 25V
Verpackung	Tube

NTD32N06L-1G ist neu im Original, Suche NTD32N06L-1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD32N06L-1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD32N06L-1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTD32N06LT4 AMI Semiconductor / ON Semiconductor NTD32N06LT4 ON/</p>	 <p>NTD32N06L-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>	 <p>NTD32N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD3808N-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 16V 12A IPAK</p>
 <p>NTD32N06-001 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A IPAK</p>	 <p>NTD32N06LT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>	 <p>NTD32N06G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 32A DPAK</p>

heiße Teile

Mehr

NTD30555L104T4G	NTD3055L	NTD3055L04T4G	NTD3055L104	NTD3055L104-1G
NTD3055L104G	NTD3055L104T4G	NTD3055L170	NTD3055L170-001	NTD3055L170-1G
NTD3055L170G	NTD3055L170T4	NTD3055L170T4G	NTD3055LT4G	NTD3055VLT4G
NTD30N02G	NTD30N02T4	NTD30N02T4G	NTD30N06RT4	NTD30N06T4G
NTD32N06-001	NTD32N06-1G	NTD32N06G	NTD32N06L	NTD32N06L-001
NTD32N06LG	NTD32N06LT4G	NTD32N06T4G	NTD3808NT4G	NTD3813NT4G
NTD3817NT4G	NTD40N03R	NTD40N03R-1	NTD40N03R-1G	NTD40N03RG
NTD40N03RT4	NTD40N03RT4G	NTD4302-001	NTD4302-001G	NTD4302-1G
NTD4302G	NTD4302T4	NTD4302T4G	NTD4804N	NTD4804NT4G
NTD4805N	NTD4805N-1G	NTD4805NT4G	NTD4806N	NTD4806N-35G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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